L6590

# FULLY INTEGRATED POWER SUPPLY FIPSTM

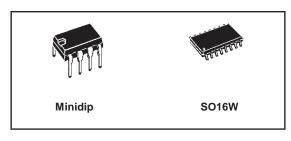
PRODUCT PREVIEW

#### **Features**

- WIDE-RANGE MAINS OPERATION
- "ON-CHIP" 700V BVDSS POWER MOS
- 65kHz INTERNAL OSCILLATOR
- 2.5V ±2% INTERNAL REFERENCE
- STANDBY MODE FOR HIGH EFFICIENCY AT LIGHT LOAD
- OVERCURRENT AND LATCHED OVERVOL-TAGE PROTECTION
- NON DISSIPATIVE BUILT-IN START-UP CIR-CUIT
- ON-CHIP SOFT START AND THERMAL SHUTDOWN

### **Main Applications**

- WALL PLUG POWER SUPPLY UP TO 15W
- AC-DC ADAPTORS
- AUXILIARY POWER SUPPLY:
  - MONITORS (BLUE ANGEL)
  - DESKTOPS/SERVERS
  - FAX, TV, LASER PRINTERS
  - HOME APPLIANCES/LIGHTING
- LINE CARD, DC-DC CONVERTERS



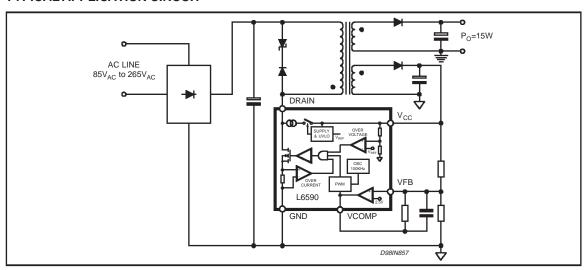
### **DESCRIPTION**

The L6590 is a monolithic switching regulator designed in BCD OFF-LINE technology, able to operate with wide range input voltage and delivering an output power up to 13W. The internal switch is implemented by a lateral high voltage power Mosfet with an Rdson of  $13\Omega$  and a BVDss of 700V. The internal fixed oscillator frequency, non dissipative start up and the internal soft start system allow to minimize the components count. A 2.5V+/-2% internal reference in addition to a high gain error amplifier make the device suitable for low cost applications with primary control.

Internal protections like cycle by cycle current limiting, output overvoltage protection and thermal shutdown generate a 'robust' design solution.

The device automatically reduces the frequency from 65KHz to 22KHz under light load conditions improving the efficiency.

### **TYPICAL APPLICATION CIRCUIT**



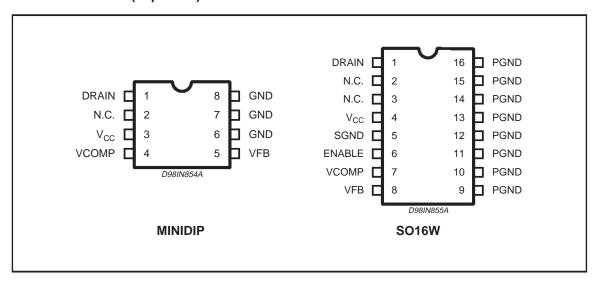
May 1999 1/8

This is preliminary information on a new product now in development. Details are subject to change without notice.

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>ds</sub>	Drain Source Voltage	700	V
l <sub>d</sub>	Drain Current	0.7	Α
V <sub>cc</sub>	Supply Voltage	18	V
	Error Amplifier Output Sink Current	3	mA
P <sub>tot</sub>	Power Dissipation at T <sub>amb</sub> < 50°C (Minidip)	1	W
T <sub>i</sub>	Junction Operating Temperature Range	-40 to 150	°C
T <sub>stg</sub>	Storage Temperature	-40 to 150	°C

# PINS CONNECTION (Top views)



### THERMAL DATA

Symbol	Parameter	Minidip	SO16W	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction to Ambient Free Air	60	-	°C/W
R <sub>th j-amb</sub>	Thermal Resistance Junction to Ambient (*)	35 to 60	35 to 60	°C/W

<sup>(\*)</sup> Value depending from PCB copper areas and thikness.

# **ELECTRICAL CHARACTERISTICS** ( $T_j = 0$ to 105 °C, $V_{cc} = 10V$ ) **Power Section**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
$BV_dss$	Drain Source Voltage	$I_{d} = 500 \mu A$	700			V
I <sub>dss</sub>	Off State Drain Current	V <sub>ds</sub> = 560V			500	μΑ
R <sub>dson</sub>	Drain Source on state	$I_d = 25 \text{mA}; Tj = 25^{\circ}\text{C}$		13	17	Ω
	Resistance	Tj = 125°C		26	35	Ω

# **ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Error Amp	Section					
$V_{fb}$	Input Voltage	Tj = 25°C	2.45	2.5	2.55	V
	'	Tj = 125°C	2.43	2.5	2.57	V
I <sub>b</sub>	Input Bias Current			-0.3	-1	μА
	Avol		60			dB
В	Unity Gain Bandwidth		0.7	1		MHz
SVR	Supply Voltage Rejection			70		dB
I <sub>source</sub>	Output Source Current	Vcomp = 3.5V	0.5	1		mA
$V_{oh}$	V <sub>out</sub> High	$I_{\text{source}} = 0.5 \text{mA} \ V_{\text{fb}} = 2 \text{V}$	3.8	4.5		V
$V_{ol}$	V <sub>out</sub> Low	$I_{sink} = 1mA V_{fb} = 3V$			1.0	V
Oscillator S	Section					
Fosc	Oscillator Frequency	Tj = 25°C	58	65	72	KHz
000	,		56	65	74	KHz
Dmin	Min. Duty Cycle	Vcomp = 1V			0	%
Dmax	Max. Duty Cycle		66	70	74	%
	eration Section	I				,,,
I <sub>op</sub>	Operating Supply Current			6	8	mA
I <sub>psc</sub>	Peak Start up Current	V <sub>cc</sub> = 0V	5	10	15	mA
Vz	Zener Voltage	V CC — U V	17	17.5	18	V
V <sub>ddon</sub>	Start Threshold Voltage		14	14.5	15	V
V <sub>ddoff</sub>	Min Operating Voltage After Turn on		7	7.5	8	V
Soft Start						
V <sub>ccss</sub>	Soft Start Threshold Voltage		12	12.5	13	V
Circuit Pro		I		12.5		<u> </u>
I <sub>lim</sub>	Pulse by Pulse Current Limit	dI/dt = 0.2A/μs	500	625	700	mA
OVP	Over Voltage Protection	αι/αι = 0.2/ γμο	15	15.5	16	V
t <sub>m</sub>	Internal Masking Time		<del>   </del>	120	1	ns
Stand by S	•		<u> </u>	120		110
	Current Threshold for Stand-By	Transition from 65KHz to		70		mA
I <sub>pksb</sub>	Operation	22KHz		'		'''^
F <sub>stb</sub>	Stand by Frequency	Tj = 25°C	19	23	27	KHz
I <sub>pknor</sub>	Current Threshold for Normal Operation	Transition from 22KHz to 65KHz		170		mA
	Stand by current	f <sub>SW</sub> = fstand-by		5	7.5	mA
PN/OFF/RR	OWN-OUT	1 011				
V <sub>th on</sub>	Threshold Voltage (Device on)		2.425	2.5	2.575	V
I <sub>Hyst</sub>	Source Current	$V_{pin} = 3V$	30	50	70	μА
I <sub>off</sub>	Supply Current in Off Condition	$V_{pin} = 3V$		0.5	<del>                                     </del>	mΑ
I <sub>p</sub>	Source Current	$V_{pin} = 2V$ $V_{pin} = 2V$	_	5	<del>                                     </del>	mA
	On/Off Clamp Pull-Up Voltage	$I_{\text{sink}} = 0.5\text{mA}$	5	5.5	6	V
V <sub>CL</sub>		I ISINK = U.SITIA	l o	J 5.5	1 0	ı v
INEKWAL	SHUTDOWN (*)	Г	450	105		۰۰
	Thermal Shutdown		150	165	-	°C
	Hysteresis	l		40		°C

<sup>(\*)</sup> Parameter not tested in production.



### **APPLICATION EXAMPLES**

Figure 1. AC-DC Adaptor, Auxiliary P.S. (Isolated bias winding feedback)

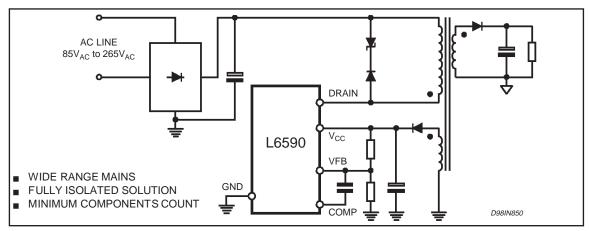


Figure 2. High Performance AC-DC Converter. (Secondary referenced optcoupler feedback)

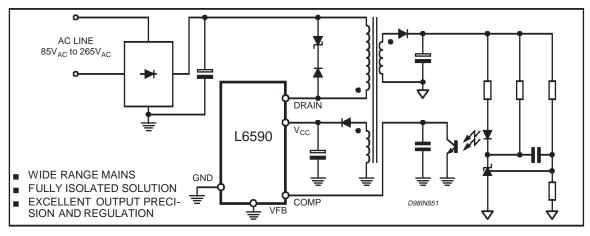
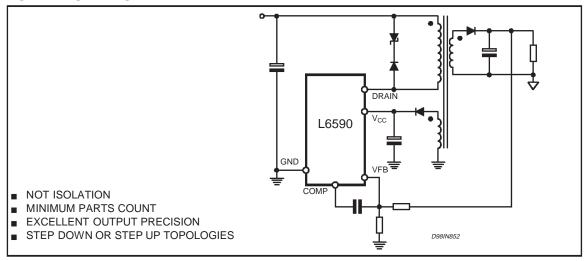
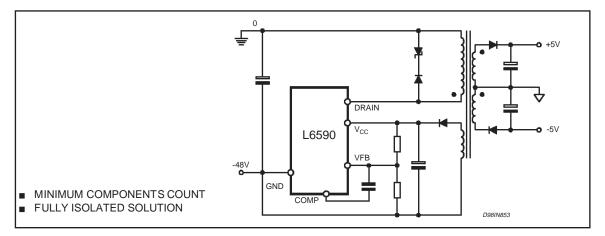


Figure 3. High Voltage DC-DC Converter.



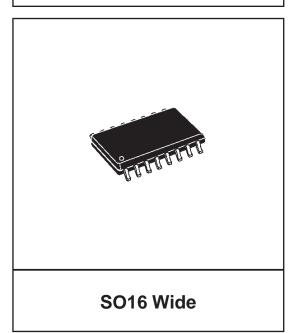
# **APPLICATION EXAMPLE (continued)**

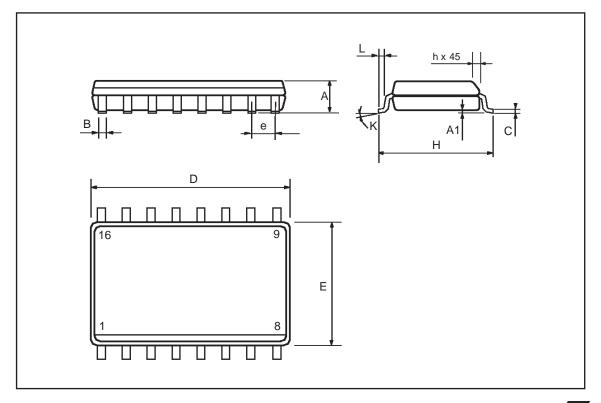
# Figure 4. Line Card Application. (Isolated bias winding feedback)



DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	2.35		2.65	0.093		0.104
A1	0.1		0.3	0.004		0.012
В	0.33		0.51	0.013		0.020
С	0.23		0.32	0.009		0.013
D	10.1		10.5	0.398		0.413
E	7.4		7.6	0.291		0.299
е		1.27			0.050	
Н	10		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.4		1.27	0.016		0.050
К	0° (min.)8° (max.)					

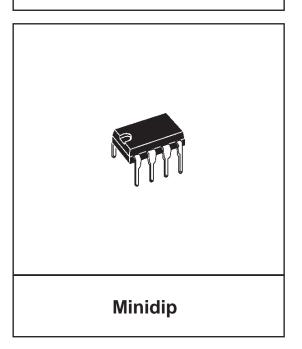
# OUTLINE AND MECHANICAL DATA

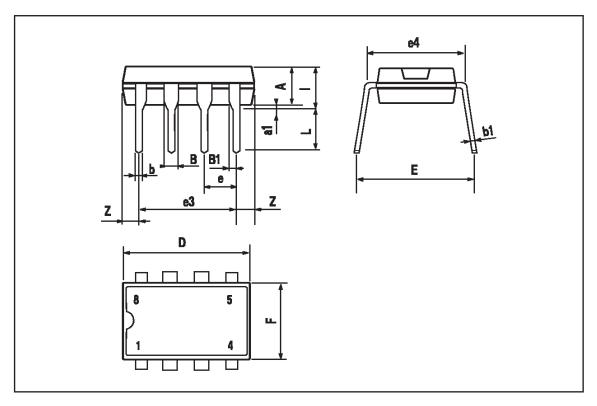




DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α		3.32			0.131	
a1	0.51			0.020		
В	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
Е	7.95		9.75	0.313		0.384
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I		·	5.08			0.200
L	3.18	·	3.81	0.125		0.150
Z			1.52			0.060

# OUTLINE AND MECHANICAL DATA





Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 1999 STMicroelectronics - Printed in Italy - All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A. http://www.st.com

4